

TECHNICAL DATA SHEET

6 Lake Street, Lawrence, MA 01841 1-800-446-1158 / (978) 620-2600 / Fax: (978) 689-0803 Website: http://www.microchip.com

DEVICES

* 1N5629 thru 1N5665 1N5629A thru 1N5665A

* Commercial only

DESCRIPTION

This popular Transient Voltage Suppressor (TVS) series for 1N5629 thru 1N5665A are JEDEC registered selections for unidirectional devices. All have the same high Peak Pulse Power rating of 1500 W with extremely fast response times. They are also available in military qualified selections as described in the Features section herein. They are most often used for protecting against transients from inductive switching environments, induced RF effects, or induced secondary lightning effects as found in lower surge levels of IEC61000-4-5. They are also very successful in protecting airborne avionics and electrical systems. Since their response time is virtually instantaneous, they can also protect from ESD and EFT per IEC61000-4-2 and IEC61000-4-4.

IMPORTANT: For the most current data, consult *MICROSEMI's* website:

http://www.microsemi.com

FEATURES

- Unidirectional TVS series for thru-hole mounting
- Suppresses transients up to 1500 watts @ $10/1000 \mu s$ (see Figure 1)
- Clamps transient in less than 100 pico seconds
- ➤ Working voltage (V_{WM}) range 5 V to 171 V
- Hermetic sealed DO-13 metal package
- JAN/TX/TXV military qualifications also available for the tighter tolerance "A" suffix devices per MIL-PRF-19500/500 by adding the JAN, JANTX, or JANTXV prefix, e.g. JANTXV1N5629A, etc.
- For bidirectional TVS in the same DO-13 package, see separate data sheet for the 1N6036 – 1N6072A series (also military qualified)
- Surface mount equivalent packages also available as SMCJ5.0 SMCJ170CA or SMCG5.0 - SMCG170CA in separate data sheet (consult factory for other surface mount options)
- Plastic axial-leaded equivalents available in the 1N6267 1N6303A series in separate data sheet

Gort Road Business Park, Ennis, Co. Clare, Ireland Tel: +353 (0) 65 6840044 *Fax:* +353 (0) 65 6822298



LEVELS

JAN



T4-LDS-0096 Rev. 3



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APPLICATIONS / BENEFITS

- Protection from switching transients and induced RF
- ➢ ESD & EFT protection per IEC 61000-4-2 and -4-4
- Secondary lightning protection per IEC61000-4-5 with 42 Ohms source impedance:
 - Class 1: 1N5629 to 1N5665A
 - Class 2: 1N5629 to 1N5663A
 - Class 3: 1N5629 to 1N5655A
 - Class 4: 1N5629 to 1N5648A
- Secondary lightning protection per IEC61000-4-5 with 12 Ohms source impedance:
 - Class 1: 1N5629 to 1N5658A
 - Class 2: 1N5629 to 1N5651A
 - Class 3: 1N5629 to 1N5643A
 - Class 4: 1N5629 to 1N5636A
- Secondary lightning protection per IEC61000-4-5 with 2 Ohms source impedance: Class 2: 1N5629 to 1N5642A
 Class 3: 1N5629 to 1N5635A
- Inherently radiation hard per Microsemi MicroNote 050

MAXIMUM RATINGS

- ▶ 1500 Watts for 10/1000 µs with repetition rate of 0.01% or less* at lead temperature (T_L) 25°C (see Figs 1, 2, & 4)
- ➢ Operating & Storage Temperatures: -55° to +175°C
- THERMAL RESISTANCE: 50°C/W junction to lead at 0.375 inches (10 mm) from body or 110°C/W junction to ambient when mounted on FR4 PC board with 4 mm² copper pads (1oz) and track width 1 mm, length 25 mm
- > DC Power Dissipation*: 1 Watt at $T_L \le +125^{\circ}C 3/8^{\circ}$ (10 mm) from body (see derating in Fig 3 and note below)
- > Forward surge current: 200 Amps for 8.3ms half-sine wave at $T_A = +25^{\circ}C$
- Solder Temperatures: 260 ° C for 10 s (maximum)

MECHANICAL AND PACKAGING

- CASE: DO-13 (DO-202AA), welded, hermetically sealed metal and glass
- FINISH: All external metal surfaces are Tin-Lead plated and solderable per MIL-STD-750 method 2026
- > POLARITY: Cathode connected to case and polarity indicated by diode symbol
- > MARKING: Part number and polarity diode symbol
- ➢ WEIGHT: 1.4 grams. (Approx)
- > TAPE & REEL option: Standard per EIA-296 (add "TR" suffix to part number)
- See package dimension on last page
- * TVS devices are not typically used for dc power dissipation and are instead operated at or less than their rated standoff voltage

 (V_{WM}) except for transients that briefly drive the device into avalanche breakdown (V_{BR} to V_C region).



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JEDEC Type No.*	Breakdown Voltage V _(BR) @ I _(BR)		Breakdown Current I _(BR)	Rated Standoff Voltage	Maximum Standby Current	Maximum Clamping Voltage	Maximum Peak Pulse Current	Maximum Temperature Coefficient of
	Min.	Max.		Vwm	Id @ Vwm	Vc @ Ірр	Ірр	$V_{(BR)} \alpha_{V(BR)}$
	V	V	mA	V	μA	V	Α	%/°C
IN5629	6.12	7.48	10	5.50	1000	10.8	139	.057
IN5629A	6.45	7.14	10	5.80	1000	10.5	143	.057
1N5630	6.75	8.25	10	6.05	500	11.7	128	.061
IN5630A	7.13	7.88	10	6.40	500	11.3	132	.061
N5631	7.38	9.02	10	6.63	200	12.5	120	.065
N5631A	7.79	8.61	10	7.02	200	12.1	124	.065
IN5632	8.19	10.0	1	7.37	50	13.8	109	.068
IN5632A	8.65	9.55	1	7.78	50	13.4	112	.068
1N5633 1N5633A	9.00 9.5	11.0 10.5	1	8.10 8.55	10 10	15.0 14.5	100 103	.073 .073
1N5634	9.5	10.3	1	8.92	5	14.3	93	.075
1N5634A	10.5	11.6	1	9.40	5	15.6	96	.075
1N5635	10.5	13.2	1	9.72	5	17.3	87	.075
IN5635A	11.4	12.6	1	10.2	5	16.7	90	.078
1N5636	11.7	14.3	1	10.2	5	19.0	79	.078
1N5636A	12.4	13.7	1	11.1	5	18.2	82	.081
1N5637	13.5	16.5	1	12.1	5	22.0	68	.084
1N5637A	14.3	15.8	1	12.8	5	21.2	71	.084
1N5638	14.4	17.6	1	12.9	5	23.5	64	.086
1N5638A	15.2	16.8	1	13.6	5	22.5	67	.086
1N5639	16.2	19.8	1	14.5	5	26.5	56.5	.088
1N5639A	17.1	18.9	1	15.3	5	25.2	59.5	.088
1N5640	18.0	22.0	1	16.2	5	29.1	51.5	.090
IN5640A	19.0	21.0	1	17.1	5	27.7	54	.090
1N5641	19.8	24.2	1	17.8	5	31.9	47	.092
1N5641A	20.9	23.1	1	18.8	5	30.6	49	.092
1N5642	21.6	26.4	1	19.4	5	34.7	43	.094
IN5642A	22.8	25.2	1	20.5	5	33.2 39.1	45 38.5	.094
1N5643 1N5643A	24.3 25.7	29.7 28.4	1	21.8 23.1	5	39.1	38.5 40	.096 .096
IN3643A IN5644	23.7	28.4 33.0	1	23.1 24.3	5	43.5	34.5	.096
1N5644A	27.0	31.5	1	25.6	5	41.4	36	.097
1N5645	29.7	36.3	1	26.8	5	47.7	31.5	.098
IN5645A	31.4	34.7	1	28.2	5	45.7	33	.098
1N5646	32.4	39.6	1	29.1	5	52.0	29	.099
1N5646A	34.2	37.8	1	30.8	5	49.9	30	.099
IN5647	35.1	42.9	1	31.6	5	56.4	26.5	.100
IN5647A	37.1	41.0	1	33.3	5	53.9	28	.100
IN5648	38.7	47.3	1	34.8	5	61.9	24	.101
N5648A	40.9	45.2	1	36.8	5	59.3	25.3	.101
IN5649	42.3	51.7	1	38.1	5	67.8	22.2	.101
IN5649A	44.7	49.4	1	40.2	5	64.8	23.2	.101
IN5650	45.9	56.1	1	41.3	5	73.5	20.4	.102
IN5650A	48.5	53.6	1	43.6	5	70.1	21.4	.102
IN5651	50.4	61.6	1	45.4	5	80.5	18.6	.103
IN5651A IN5652	53.2	58.8	1	47.8	5	77.0	19.5	.103
N5652 N5652A	55.8 58.9	68.2 65.1	1	50.2 53.0	5 5	89.0 85.0	16.9 17.7	.104 .104
IN5652A IN5653	61.2	74.8	1	55.1	5	98.0	17.7	.104
N5653A	64.6	74.8	1	58.1	5	98.0 92.0	15.3	.104
IN5654	67.5	82.5	1	60.7	5	108	13.9	.104
N5654A	71.3	78.8	1	64.1	5	103	14.6	.105
N5655	73.8	90.2	1	66.4	5	118	12.7	.105
N5655A	77.9	86.1	1	70.1	5	113	13.3	.105
N5656	81.9	100.0	1	73.7	5	131	11.4	.106
IN5656A	86.5	95.5	1	77.8	5	125	12.0	.106
IN5657	90	110	1	81.0	5	144	10.4	.106
N5657A	95	105	1	85.5	5	137	11.0	.106
N5658	99	121	1	89.2	5	158	9.5	.107
N5658A	105	116	1	94.0	5	152	9.9	.107
N5659	108	132	1	97.2	5	173	8.7	.107
N5659A	114	126	1	102	5	165	9.1	.107
N5660	117	143	1	105	5	187	8.0	.107
N5660A	124	137	1	111	5	179	8.4	.107



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JEDEC Type No.*	Breakdown Voltage V _(BR) @ I _(BR)		Breakdown Current I _(BR)	Rated Standoff Voltage V _{WM}	Maximum Standby Current I _D @ V _{WM}	Maximum Clamping Voltage V _C @ I _{PP}	Maximum Peak Pulse Current I _{PP}	Maximum Temperature Coefficient of V(BR) αV(BR)
	Min. Max.							
	V	V	mA	V	μA	V	Α	%/°C
1N5661	135	165	1	121	5	215	7.0	.108
1N5661A	143	158	1	128	5	207	7.2	.108
1N5662	144	176	1	130	5	230	6.5	.108
1N5662A	152	168	1	136	5	219	6.8	.108
1N5663	153	187	1	138	5	244	6.2	.108
1N5663A	162	179	1	145	5	234	6.4	.108
1N5664	162	198	1	146	5	258	5.8	.108
1N5664A	171	189	1	154	5	246	6.1	.108
1N5665	180	220	1	162	5	287	5.2	.108
1N5665A	190	210	1	171	5	274	5.5	.108

NOTE 1: A TVS is normally selected according to the rated "Standoff Voltage" V_{WM} that should be equal to or greater than the dc or continuous peak operating voltage level.

NOTE 2: Also available in military qualified types with a JAN, JANTX, or JANTXV prefix.

	SYMBOLS & DEFINITIONS						
Symbol	Definition						
$V_{\rm WM}$	Standoff Voltage: Applied Reverse Voltage to assure a nonconductive condition. (See Note 1 above.)						
V _(BR)	Breakdown Voltage: This is the Breakdown Voltage the device will exhibit at 25°C						
V _C	Maximum Clamping Voltage: The maximum peak voltage appearing across the TVS when subjected to the peak pulse current in a one millisecond time interval. The peak pulse voltage is the combination of voltage rise due to both the series resistance and thermal rise and positive temperature coefficient ($\alpha_{V(BR)}$)						
I_{PP}	Peak Pulse Current: The peak current during the impulse (See Figure 2)						
P _{PP}	Peak Pulse Power: The pulse power as determined by the product of V_C and I_{PP}						
I _D	Standby Current: The current at the standoff voltage (V_{WM})						
I(BR)	Breakdown Current: The current used for measuring Breakdown Voltage (V _(BR))						

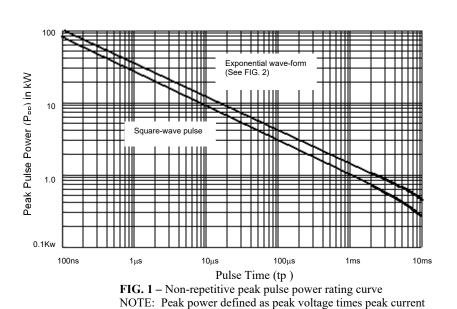


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GRAPHS



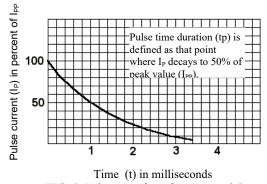


FIG. 2 Pulse wave form for exponential surge

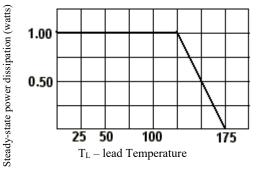
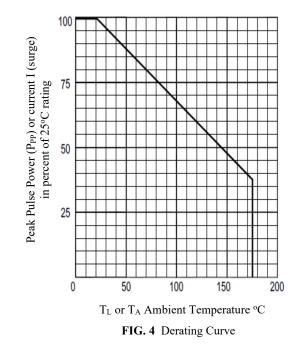


FIG. 3 Steady-state power derating curve

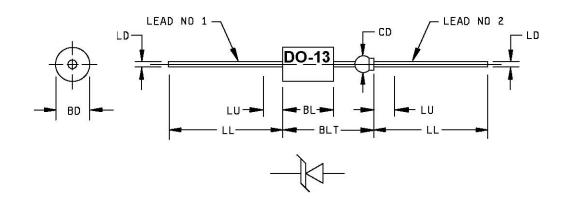




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PACKAGE DIMENSIONS



NOTES:

- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. The major diameter is essentially constant along its length.
- 4. Within this zone, diameter may vary to allow for lead finishes and irregularities.
- 5. Dimension to allow for pinch or seal deformation anywhere along tubulation.
- 6. Lead 1 (cathode) shall be electrically connected to the case.
- 7. In accordance with ASME Y14.5M, diameters are equivalent to φx symbology.

Symbol	Inc	hes	Millimeters		Notes
	Min	Max	Min	Max	
BD	.215	.235	5.46	5.97	
BL	.293	.357	7.44	9.07	3
BLT		.570		14.48	
CD	.045	.100	1.14	2.54	5
LD	.025	.035	0.64	0.89	
LL	1.000	1.625	25.40	41.28	4
LU		.188		4.78	4

FIGURE 1. Physical dimensions (DO-13).